

# **Operational Amplifiers**

# Low Voltage Operation Ground Sense Operational Amplifiers



# General Description

TLR341G is single CMOS Op-Amp with shutdown function, low supply voltage operation and output full swing. There are suitable for battery equipment. MOS-FET input stage provide low input bias current. It is capable to use for sensor applications.

#### Features

- Low operating supply voltage
- Full swing Output Swing
- High large signal voltage gain
- Low input bias current
- Low supply current
- Low input offset voltage

#### Applications

- Customer electronics
- Buffer
- Active filter
- Mobile equipment
- Battery equipment

#### Key Specifications

■ Low Operating Supply Voltage (single supply):

+1.8V to +5.0V

Low Supply Current: 70uA
Low Shutdown Current: 0.2nA (Typ.)
High voltage gain (RL=2kΩ): 105dB(Typ.)

■ Wide Temperature Range: -40°C to +85°C
■ Turn on time from shutdown: 5µs (Typ.)

■ Low Input Offset Voltage: 4mV (Max.)
■ Low Input Bias Current: 1pA (Typ.)

■ Gain Bandwidth: 2.3MHz (Typ.)
■ Slew Rate: 0.9V/µs (Typ.)

● Package W(Typ.) xD(Typ.) xH(Max.) SSOP6 2.90mm x 2.80mm x 1.25mm

#### Simplified Schematic

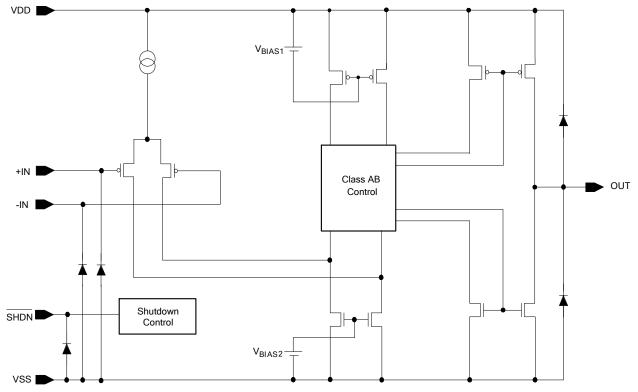
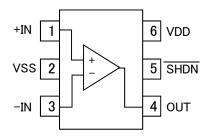


Figure 1. Simplified Schematic (1 channel only)

OProduct structure: Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays.

# ●Pin Configuration

TLR341G: SSOP6



Pin No.	Pin Name			
1	+IN			
2	VSS			
3	-IN			
4	OUT			
5	SHDN			
6	VDD			

Package
SSOP6
TLR341G

#### **●Shutdown**

71.010.01.11		
Pin	Input condition	State
	VSS	Shutdown
SHDN	VDD	Active

Note: Please refer to Electrical Characteristics regarding the turn on and off voltage.

Ordering Information



●Line-up

Topr	Pack	age	Operable Part Number
-40°C to +85°C	SSOP6	Reel of 3000	TLR341G-TR

● Absolute Maximum Ratings(Ta=25°C)

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Parameter	Symbol	Ratings	Unit
Supply Voltage	VDD-VSS	+5.5	V
Power dissipation	Pd	675 <sup>*1*2</sup>	mW
Differential Input Voltage*3	Vid	VDD to VSS	V
Input Common-mode Voltage Range	Vicm	(VSS – 0.3) to (VDD + 0.3)	V
Operable with low voltage	Vopr	+1.8 to +5.0	V
Operating Temperature	Topr	- 40 to +85	°C
Storage Temperature	Tstg	- 55 to +150	°C
Maximum Junction Temperature	Tjmax	+150	°C

Note: Absolute maximum rating item indicates the condition which must not be exceeded.

Application of voltage in excess of absolute maximum rating or use out absolute maximum rated temperature environment may cause deterioration of characteristics.

- \*1 To use at temperature above Ta=25°C reduce 5.4mW/°C.
- \*2 Mounted on a FR4 glass epoxy PCB(70mmx70mmx1.6mm).
- \*3 The voltage difference between inverting input and non-inverting input is the differential input voltage. Then input terminal voltage is set to more than VSS.

# ● Electrical Characteristics:

OTLR341G (Unless otherwise specified VDD=+1.8V, VSS=0V, SHDN=VDD)

Parameter	Symbol	Temperature Range	Min.	Limits Typ.	Max.	Unit	Condition
	+	25°C	-	0.3	4		
Input offset voltage*4*5	Vio	Full Range	-	-	4.5	mV	-
Input offset voltage drift <sup>*4</sup>	ΔVio/ΔΤ	25°C		1.9	-	μV/°C	-
Input bias current*4	lb	25°C	-	1	-	рА	-
Input offset current*4	lio	25°C	-	1	-	рА	-
Supply current	IDD	25°C Full Range	-	70 -	150 200	μΑ	-
Shutdown Current	IDD_SD	25°C	-	0.2	1000	nA	SHDN=0V
Common mode rejection ratio	CMRR	25°C	60	85	-	dB	VCM=0V to 0.7V
Power supply rejection ratio	PSRR	25°C	75	95	-	dB	VDD=1.8V to 5.0V
Input common mode voltage range	Vicm	25°C	VSS	-	VDD-1.1	V	CMRR ≥ 60 dB
Large signal voltage gain	Av	25°C	70	110 100	-	dB	RL=10kΩ to 0.9V RL=2kΩ to 0.9V
Maximum Output Voltage(High)	VOH	25°C	-	25 7	50 20	mV	RL= $2k\Omega$ to 0.9V RL= $10k\Omega$ to 0.9V
Maximum Output Voltage(Low)	VOL	25°C	-	22 14	55 20	mV	RL= $2k\Omega$ to 0.9V RL= $10k\Omega$ to 0.9V
Output source current*6	Isource	25°C	6	9	-	mA	OUT=0V, short current
Output sink current*6	Isink	25°C	10	15	-	mA	OUT=1.8V, short current
Slew rate	SR	25°C	-	0.9	-	V/µs	RL=10kΩ, VIN=0.7V <sub>P-P</sub>
Gain band width	GBW	25°C	-	2.2	-	MHz	CL=200pF, RL=100kΩ
Unit gain frequency	fτ	25°C	-	1.5	-	MHz	CL=200pF, RL=100kΩ
Phase margin	θ	25°C	-	55	-	deg	CL=20pF, RL=100kΩ
Gain margin	GM	25°C	-	7	-	dB	CL=20pF, RL=100kΩ
Input referred noise voltage	Vn	25°C	-	33	-	nV/√Hz	f=1kHz
Total harmonic distortion + Noise	THD+N	25°C	-	0.015	-	%	$VIN=1V_{P-P}$ , $f=1kHz$ $RL=600\Omega$ Av=0dB, DIN-AUDIO
Turn-on Time from Shutdown	Ton	25°C	-	5	-	μs	-
Turn On Voltage High	VSHDN_H	25°C	-	1.2	-	V	-
Turn On Voltage Low	VSHDN_L	25°C	-	0.5	-	V	-

Absolute value

<sup>\*5</sup> \*6

Full range: Ta=-40°C to +85°C
Under the high temperature environment, consider the power dissipation of IC when selecting the output current.
When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

OTLR341G (Unless otherwise specified VDD=+5V, VSS=0V, SHDN=VDD)

Parameter	Symbol	Temperature Range	Min.	Limits Typ.	Max.	Unit	Condition
Input offset voltage*7*8	Vio	25°C Full Range	-	0.3	4 4.5	mV	-
Input offset voltage drift*7	ΔVio/ΔΤ	25°C	-	1.9	-	μV/°C	-
Input bias current <sup>*7</sup>	lb	25°C	-	1	-	pA	-
Input offset current*7	lio	25°C	-	1	-	pA	-
Supply current	IDD	25°C Full Range	-	75 -	150 200	μΑ	-
Shutdown Current	IDD_SD	25°C	-	0.2	1000	nA	SHDN=0V
Common mode rejection ratio	CMRR	25°C	75	90	-	dB	VCM=0V to 3.9V
Power supply rejection ratio	PSRR	25°C	75	95	-	dB	VDD=1.8V to 5.0V
Input common mode voltage range	Vicm	25°C	VSS	-	VDD-1.1	V	CMRR ≥70 dB
Large signal voltage gain	Av	25°C	80	110 105	-	dB	RL=10kΩ to 2.5V RL=2kΩ to 2.5V
Maximum Output Voltage(High)	VOH	25°C	-	25 7	60 15	mV	RL= $2k\Omega$ to 2.5V RL= $10k\Omega$ to 2.5V
Maximum Output Voltage(Low)	VOL	25°C	-	40 18	60 30	mV	RL= $2k\Omega$ to 2.5V RL= $10k\Omega$ to 2.5V
Output source current*9	Isource	25°C	60	100	-	mA	OUT=0V, short current
Output sink current*9	Isink	25°C	80	120	-	mA	OUT=2.5V, short current
Slew rate	SR	25°C	-	1	-	V/µs	RL=10kΩ, VIN=2V <sub>P-P</sub>
Gain band width	GBW	25°C	-	2.3	-	MHz	CL=200pF, RL=100kΩ
Unit gain frequency	f <sub>T</sub>	25°C	-	1.6	-	MHz	CL=200pF, RL=100kΩ
Phase margin	θ	25°C	-	55	-	deg	CL=20pF, RL=100kΩ
Gain margin	GM	25°C	-	7	-	dB	CL=20pF, RL=100kΩ
Input referred noise voltage	Vn	25°C	-	33	-	nV/√Hz	f=1kHz
Total harmonic distortion + Noise	THD+N	25°C	-	0.012	-	%	$VIN=1V_{P-P}$ , $f=1kHz$ $RL=600\Omega$ , Av=0dB, DIN-AUDIO
Turn-on Time from Shutdown	Ton	25°C	-	15	-	μs	-
Turn On Voltage High	VSHDN_H	2500	-	3.4	-	V	-
Turn On Voltage Low	VSHDN_L	25°C	-	1.2	-	V	-

Absolute value \*7

Full range: Ta=-40°C to +85°C

<sup>\*8</sup> \*9 Under the high temperature environment, consider the power dissipation of IC when selecting the output current. When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

#### **Description of electrical characteristics**

Described here are the terms of electric characteristics used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacture's document or general document.

#### 1. Absolute maximum ratings

Absolute maximum rating item indicates the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

1.1 Power supply voltage (VDD/VSS)

Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.

1.2 Differential input voltage (Vid)

Indicates the maximum voltage that can be applied between non-inverting terminal and inverting terminal without deterioration and destruction of characteristics of IC.

1.3 Input common-mode voltage range (Vicm)

Indicates the maximum voltage that can be applied to non-inverting terminal and inverting terminal without deterioration or destruction of characteristics. Input common-mode voltage range of the maximum ratings not assures normal operation of IC. When normal Operation of IC is desired, the input common-mode voltage of characteristics item must be followed.

1.4 Power dissipation (Pd)

Indicates the power that can be consumed by specified mounted board at the ambient temperature 25°C(normal temperature). As for package product, Pd is determined by the temperature that can be permitted by IC chip in the package (maximum junction temperature) and thermal resistance of the package.

#### 2. Electrical characteristics item

2.1 Input offset voltage (Vio)

Indicates the voltage difference between non-inverting terminal and inverting terminal. It can be translated into the input voltage difference required for setting the output voltage at 0 V.

2.2 Input offset voltage drift (ΔVio/ΔT)

Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.

2.3 Input bias current (Ib)

Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias current at non-inverting terminal and input bias current at inverting terminal.

2.4 Input offset current (lio)

Indicates the difference of input bias current between non-inverting terminal and inverting terminal.

2.5 Supply current (IDD)

Indicates the IC current that flows under specified conditions and no-load steady status.

2.6 Shutdown current (IDD\_SD)

Indicates the current when the circuit is shutdown.

2.7 Common-mode rejection ratio (CMRR)

Indicates the ratio of fluctuation of input offset voltage when in-phase input voltage is changed. It is normally the fluctuation of DC.

CMRR = (Change of Input common-mode voltage)/(Input offset fluctuation)

2.8 Power supply rejection ratio (PSRR)

Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC. PSRR= (Change of power supply voltage)/(Input offset fluctuation)

2.9 Input common-mode voltage range (Vicm)

Indicates the input voltage range where IC operates normally.

2.10 Large signal voltage gain (Av)

Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.

Av = (Output voltage) / (Differential Input voltage)

2.11 Maximum Output Voltage(High) / Maximum Output Voltage(Low) (VOH/VOL)

Indicates the voltage range that can be output by the IC under specified load condition. It is typically divided into maximum output voltage High and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.

2.12 Output source current/ output sink current (Isource / Isink)

The maximum current that can be output under specific output conditions, it is divided into output source current and output sink current. The output source current indicates the current flowing out of the IC, and the output sink current the current flowing into the IC.

2.13 Slew Rate (SR)

SR is a parameter that shows movement speed of operational amplifier. It indicates rate of variable output voltage as unit time.

2.14 Gain Band Width (GBW)

Indicates to multiply by the frequency and the gain where the voltage gain decreases 6dB/octave.

2.15 Unity gain frequency (f<sub>T</sub>)

Indicates a frequency where the voltage gain of operational amplifier is 1.

- 2.16 Phase Margin (θ)
  - Indicates the margin of phase from 180 degree phase lag at unity gain frequency.
- 2.17 Gain Margin (GM)
  - Indicates the difference between 0dB and the gain where operational amplifier has 180 degree phase delay.
- 2.18 Input referred noise voltage (Vn)
  - Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input terminal.
- 2.19 Total harmonic distortion + Noise (THD+N)
  - Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.
- 2.20 Turn On Time From Shutdown (Ton)
  - Indicates the time from applying the voltage to shutdown terminal until the IC is active.
- 2.21 Turn On Voltage / Turn Off Voltage (VSHDN\_H/ VSHDN\_L)
  - The IC is active if the shutdown terminal is applied more than Turn On Voltage (VSHDN\_H).
  - The IC is shutdown if the shutdown terminal is applied less than Turn Off Voltage (VSHDN\_L).

# ●Typical Performance Curves OTLR341G

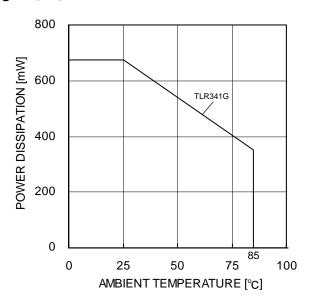


Figure 2.
Derating curve

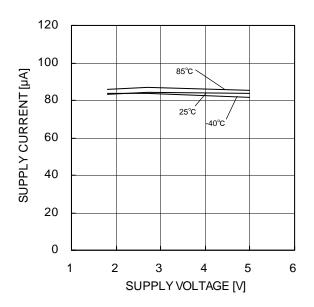


Figure 3.
Supply Current – Supply Voltage

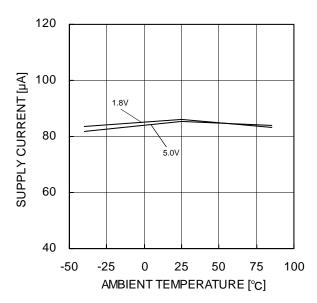


Figure 4.
Supply Current – Ambient Temperature

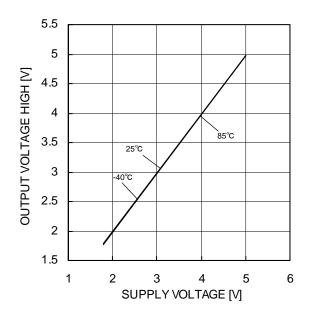


Figure 5. Maximum Output Voltage High – Supply Voltage (RL=2kΩ)

# ● Typical Performance Curves (Reference data) – Continued OTLR341G

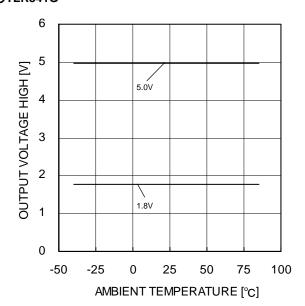


Figure 6.

Maximum Output Voltage High –

Ambient Temperature

(RL=2kΩ)

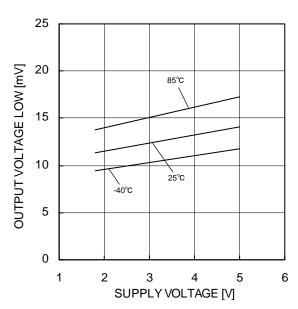


Figure 7.

Maximum Output Voltage Low –

Supply Voltage

(RL=2kΩ)

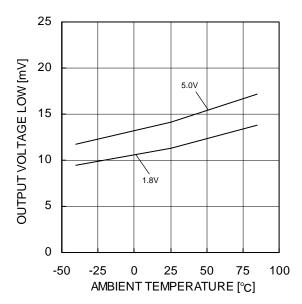


Figure 8.

Maximum Output Voltage Low –

Ambient Temperature

(RL=2kΩ)

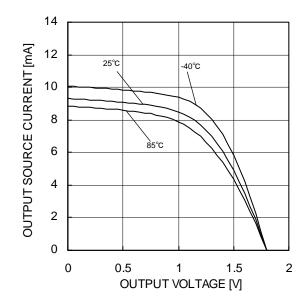


Figure 9.
Output Source Current – Output Voltage (VDD=1.8V)

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# ● Typical Performance Curves (Reference data) – Continued OTLR341G

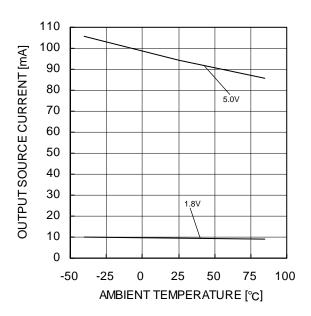


Figure 10.
Output Source Current –Ambient Temperature (OUT=0V)

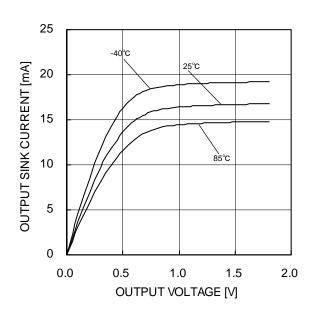


Figure 11.
Output Sink Current – Output Voltage
(VDD=1.8V)

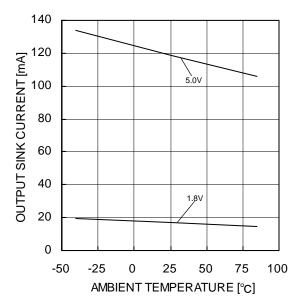


Figure 12.
Output Sink Current – Ambient Temperature (OUT=VDD)

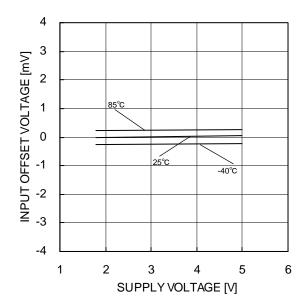


Figure 13.
Input Offset Voltage – Supply Voltage

TLR341G Datasheet

# 

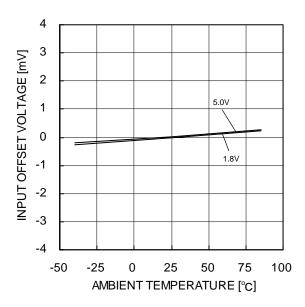


Figure 14.
Input Offset Voltage – Ambient Temperature

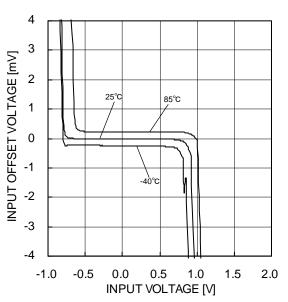


Figure 15.
Input Offset Voltage – Input Voltage (VDD=1.8V)

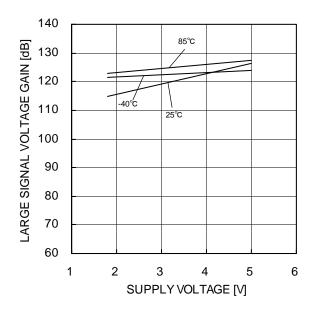


Figure 16. Large Signal Voltage Gain – Supply Voltage  $(RL=2\ k\Omega)$ 

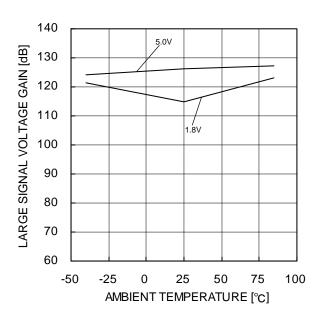


Figure 17. Large Signal Voltage Gain – Ambient Temperature (RL=2  $k\Omega$ )

(\*)The data above is measurement value of typical sample, it is not guaranteed.

TLR341G Datasheet

# ● Typical Performance Curves (Reference data) – Continued OTLR341G

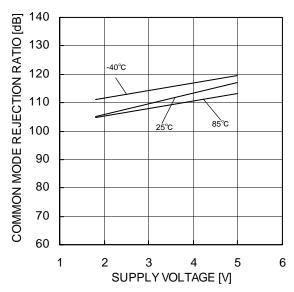


Figure 18.

Common Mode Rejection Ratio – Supply Voltage (VDD=1.8V)

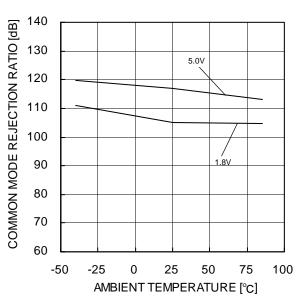


Figure 19.
Common Mode Rejection Ratio – Ambient Temperature

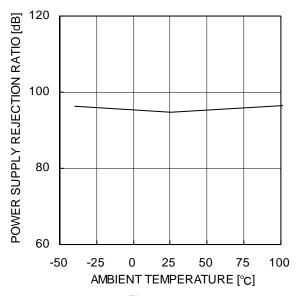


Figure 20.
Power Supply Rejection Ratio – Ambient Temperature (VDD=1.8V ~ 5.0V)

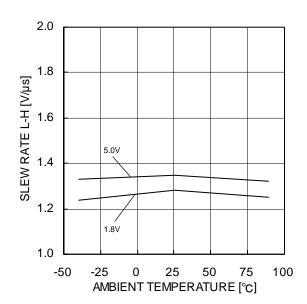


Figure 21. Slew Rate L-H – Ambient Temperature

(\*)The data above is measurement value of typical sample, it is not guaranteed.

# ● Typical Performance Curves (Reference data) - Continued OTLR341G

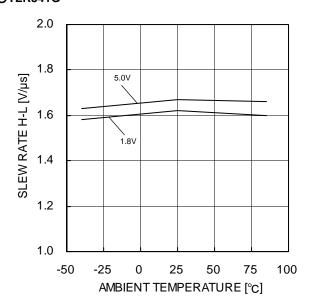


Figure 22.
Slew Rate H-L – Ambient Temperature

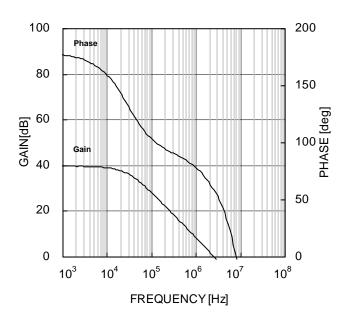
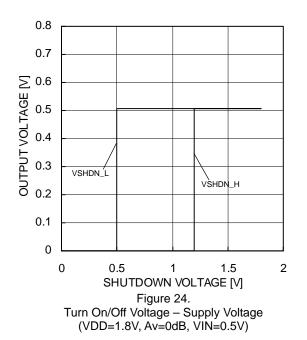
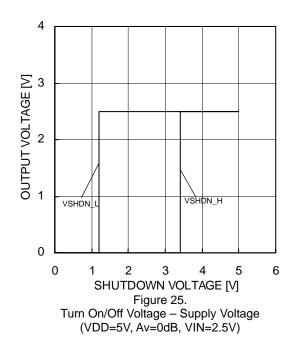


Figure 23.
Voltage Gain, Phase – Frequency
(VDD=1.8V, 25°C)





(\*)The data above is measurement value of typical sample, it is not guaranteed.

# ●Application Information NULL method condition for Test Circuit 1

						VD	D, VSS	, EK, Vi	cm Unit:V
Parameter	VF	S1	S2	S3	VDD	VSS	EK	Vicm	Calculation
Input Offset Voltage		ON	ON	OFF	2.4	0	-1.2	0.5	1
Larga Cignal Voltage Coin	VF2	ON	011	011	5	0	-0.5	2.5	2
Large Signal Voltage Gain	VF3 ON	ON	ON	5	0	-3.5	∠.5	2	
Common-mode Rejection Ratio	VF4	ON	ON	N OFF	OFF 6	0	-3	0	3
(Input Common-mode Voltage Range)	VF5							5	3
Power Supply Rejection Ratio	VF6	ON	ON	OFF	2.4	0	-1.2	0.5	4
Town Supply Rejection Ratio	VF7				6.0		1.2	0.5	4

- Calculation-
- 1. Input Offset Voltage (Vio)

$$Vio = \frac{|VF1|}{1 + RF/RS} [V]$$

2. Large Signal Voltage Gain(Av)

$$Av = 20Log \frac{2 \times (1+RF/RS)}{|VF2-VF3|} [dB]$$

3. Common-mode Rejection Ratio (CMRR)

$$CMRR=20Log \frac{3 \times (1+RF/RS)}{|VF4-VF5|} [dB]$$

4. Power Supply Rejection Ratio (PSRR)

$$PSRR = 20Log \frac{3.2 \times (1 + RF/RS)}{|VF6 - VF7|} [dB]$$

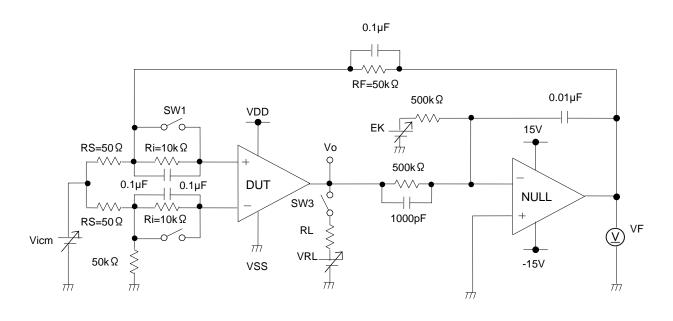


Figure 26. Test circuit 1

# **Switch Condition for Test Circuit 2**

<u> </u>												
SW No.	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8	SW9	SW10	SW11	SW12
Supply Current	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF
Maximum Output Voltage RL=10kΩ	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF
Output Current	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF
Slew Rate	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	ON
Unit gain frequency	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	ON	OFF	OFF	ON

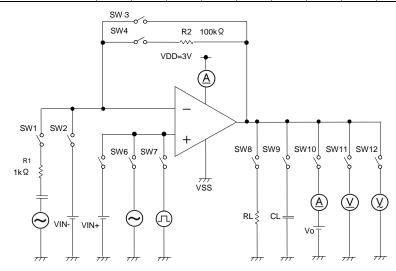


Figure 27. Test circuit 2

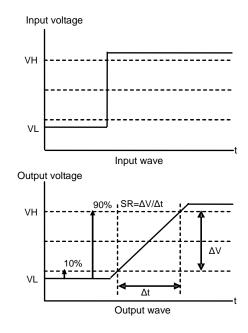


Figure 28. Slew rate input output wave

# Application example

OVoltage follower

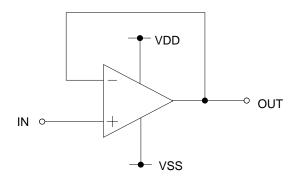


Figure 29. Voltage follower

Voltage gain is 0 dB.

This circuit controls output voltage (OUT) equal input voltage (IN), and keeps OUT with stable because of high input impedance and low output impedance.

OUT is shown next expression.

OUT=IN

# OInverting amplifier

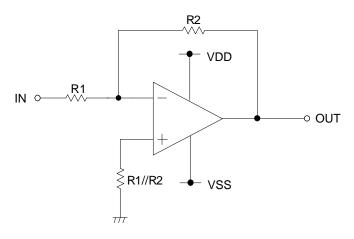


Figure 30. Inverting amplifier circuit

For inverting amplifier, Vi(b) Derating curve voltage gain decided R1 and R2, and phase reversed voltage is output.

OUT is shown next expression.

OUT=-(R2/R1) • IN

Input impedance is R1.

# ONon-inverting amplifier

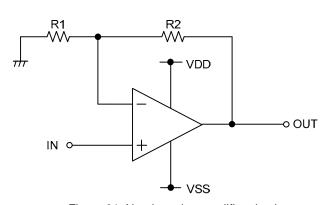


Figure 31. Non-inverting amplifier circuit

For non-inverting amplifier, IN is amplified by voltage gain decided R1 and R2, and phase is same with IN. OUT is shown next expression.

OUT=(1 + R2/R1) • IN

This circuit performes high input impedance because Input impedance is operational amplifier's input Impedance.

Datasheet

#### Power Dissipation

Power dissipation (total loss) indicates the power that can be consumed by IC at Ta=25 (normal temperature).IC is heated when it consumed power, and the temperature of IC ship becomes higher than ambient temperature. The temperature that can be accepted by IC chip depends on circuit configuration, manufacturing process, and consumable power is limited. Power dissipation is determined by the temperature allowed in IC chip (maximum junction temperature) and thermal resistance of package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage temperature range. Heat generated by consumed power of IC radiates from the mold resin or lead frame of the package. The parameter which indicates this heat dissipation capability (hardness of heat release) is called thermal resistance, represented by the symbol  $\theta$ ja $^{\circ}$ C/W. The temperature of IC inside the package can be estimated by this thermal resistance.

Figure 32.(a) shows the model of thermal resistance of the package. Thermal resistance θja, ambient temperature Ta, maximum junction temperature Tjmax, and power dissipation Pd can be calculated by the equation below:

$$\theta_{ja} = (T_{jmax} - T_{a}) / P_{d}$$
 °C/W · · · · · (I)

Derating curve in Figure 32.(b) indicates power that can be consumed by IC with reference to ambient temperature. Power that can be consumed by IC begins to attenuate at certain ambient temperature. This gradient is determined by thermal resistance  $\theta$ ja. Thermal resistance  $\theta$ ja depends on chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 33.(c) show a derating curve for an example of TLR341G.

Power dissipation of LSI [W]

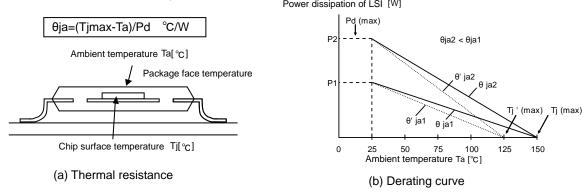
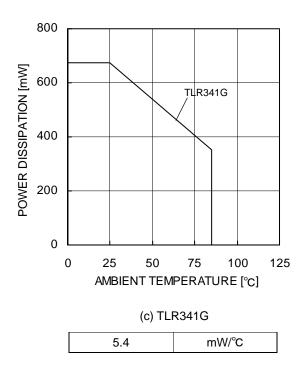


Figure 32. Thermal resistance and derating



When using the unit above Ta=25°C, subtract the value above per degree°C. Permissible dissipation is the value when FR4 glass epoxy board 70mm × 70mm × 1.6mm (cooper foil area below 3%) is mounted

Figure 33. Derating Curve

# Operational Notes

#### 1) Unused circuits

When there are unused circuits it is recommended that they are connected as in Figure 34., setting the non-inverting input terminal to a potential within input common-mode voltage range (Vicm).

#### 2) Applied voltage to the input terminal

For normal circuit operation of voltage comparator, please input voltage for its input terminal within input common mode voltage VDD + 0.3V. Then, regardless of power supply voltage, VSS-0.3V can be applied to input terminals without deterioration or destruction of its characteristics.

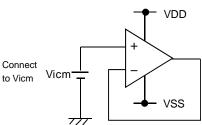


Figure. 34. The example of application circuit for unused op-amp

#### 3) Power supply (single / dual)

The op-amp operates when the specified voltage supplied is between VDD and VSS. Therefore, the single supply op-amp can be used as dual supply op-amp as well.

#### 4) Power dissipation Pd

Using the unit in excess of the rated power dissipation may cause deterioration in electrical characteristics due to a rise in chip temperature, including reduced current capability. Therefore, please take into consideration the power dissipation (Pd) under actual operating conditions and apply a sufficient margin in thermal design. Refer to the thermal derating curves for more information.

# 5) Short-circuit between pins and erroneous mounting

Incorrect mounting may damage the IC. In addition, the presence of foreign particles between the outputs, the output and the power supply, or the output and GND may result in IC destruction.

# 6) Operation in a strong electromagnetic field

Operation in a strong electromagnetic field may cause malfunctions.

#### 7) IC handling

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations in the electrical characteristics due to piezo resistance effects.

# 8) Board inspection

Connecting a capacitor to a pin with low impedance may stress the IC. Therefore, discharging the capacitor after every process is recommended. In addition, when attaching and detaching the jig during the inspection phase, ensure that the power is turned OFF before inspection and removal. Furthermore, please take measures against ESD in the assembly process as well as during transportation and storage.

#### 9) Output capacitor

Discharge of the external output capacitor to VCC is possible via internal parasitic elements when VCC is shorted to VEE, causing damage to the internal circuitry due to thermal stress. Therefore, when using this IC in circuits where oscillation due to output capacitive load does not occur, such as in voltage comparators, use an output capacitor with a capacitance less than  $0.1\mu F$ .

Designed negative feedback circuit using this IC, verify output oscillation caused by capacitive load.

#### 10) Latch up

Be careful of input voltage that exceed the VDD and VSS. When CMOS device have sometimes occur latch up operation. And protect the IC from abnormaly noise

## 11) Decupling capacitor

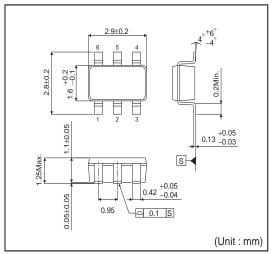
Insert the decupling capacitance between VDD and VSS, for stable operation of operational amplifier.

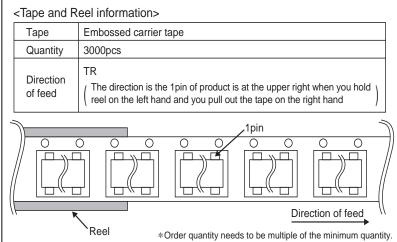
#### 12) Shutdown Terminal

The shutdown terminal can't be left unconnected. In case shutdown operation is not needed, the shutdown pin should be connected to VDD when the IC is used. Leaving the shutdown pin floating will result in an undefined operation mode, either shutdown or active, or even oscillating between the two modes.

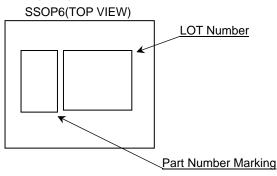
# Physical Dimensions Tape and Reel Information

# SSOP6



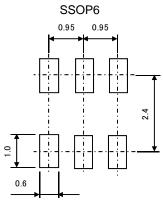


# Marking Diagram



Product	Name	Package Type	Marking		
TLR341	G	SSOP6	ВС		

# ●Land Pattern data



<del></del>				Unit: mm
PKG	Land Pitch e	Land Space MIE	Land Length ≧ℓ 2	Land Width b2
SSOP6	0.95	2.4	1.0	0.6

# Revision History

Date	Revision	Changes
2013.2.8	001	New Release

18/18

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  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - If Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4) The Products are not subject to radiation-proof design.
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- 6) In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse) is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7) De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8) Confirm that operation temperature is within the specified range described in the product specification.
- 9) ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1) When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2) In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### ●Precaution for Storage / Transportation

- 1) Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2) Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3) Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4) Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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